

Form PTO 1449 (Modified)		U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE		ATTY DOCKET NO. 0068-0399-0		SERIAL NO. <u>09/420,524</u> <u>New Application</u>	
LIST OF REFERENCES CITED BY APPLICANT				APPLICANT Masakazu KANECHIKA, et al.			
				FILING DATE Herewith		GROUP <u>2823</u>	
<b>U.S. PATENT DOCUMENTS</b>							
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
	AA						
	AB						
	AC						
	AD						
	AE						
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						
	AL						
	AM						
	AN						
<b>FOREIGN PATENT DOCUMENTS</b>							
		DOCUMENT NUMBER	DATE	COUNTRY	TRANSLATION YES                  NO		
<u>JAG</u>	AO	6-163481	06/10/94	JAPAN (with English Abstract)		XX	
<u>JAG</u>	AP	9-260312	10/03/97	JAPAN (with English Abstract)		XX	
	AQ						
	AR						
	AS						
	AT						
	AU						
	AV						
<b>OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, etc.)</b>							
<u>JAG</u>	AW	Seigo KANEMARU, et al., "FABRICATION OF METAL-OXIDE-SEMICONDUCTOR FIELD-EFFECT-TRANSISTOR-STRUCTURED SILICON FIELD EMITTERS WITH A POLYSILICON DUAL GATE", Jpn. J. Appl. Phys., Vol. 36, Part 1, No. 12B, December 1997, pages 7736-7740					
<u>JAG</u>	AX	Yoshikazu HORI, et al., "NEW SUB-MICRON SIZE Si FIELD EMITTER ARRAYS WITH LOW OPERATION VOLTAGE", Technical Report of The Institute of Electronics Information and Communication Engineers, ED94-95, 1994-12, pages 1-8, (With English Abstract)					
	AY						
	AZ						
Examiner <u>Joanne A. Garcia</u>					Date Considered <u>July 13, 2002</u>		
*Examiner: Initial if reference is considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.							